

SSF6AG THRU SSF6JG

**ULTRAFAST EFFICIENT
GLASS PASSIVATED RECTIFIER**
VOLTAGE: 50 TO 600V CURRENT: 6.0A

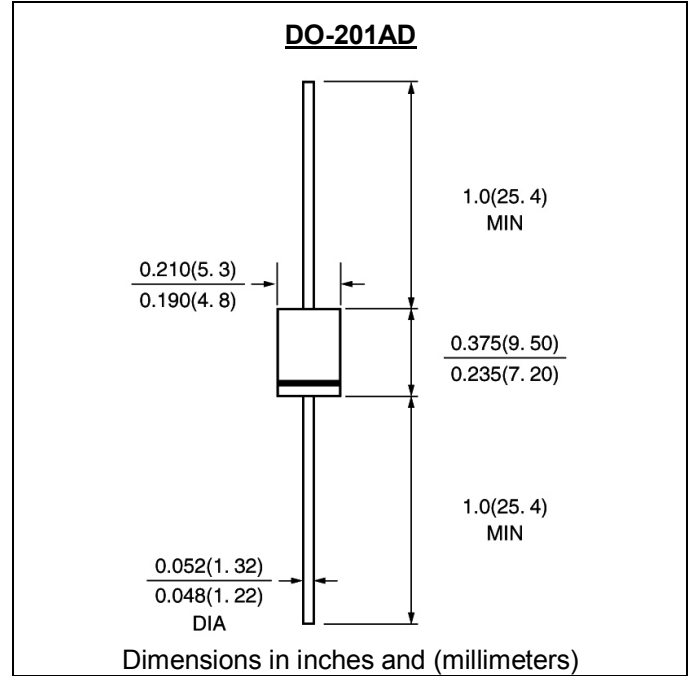


FEATURE

Low power loss
High surge capability
Ultra-fast recovery time for high efficiency
Glass passivated chip junction
High temperature soldering guaranteed
260→C/10sec/0.375"lead length at 5 lbs tension

MECHANICAL DATA

Terminal: Plated axial leads solderable per J-STD-002
Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
Polarity: color band denotes cathode
Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half -wave, 60HZ, resistive or inductive load rating at 25→C, unless otherwise stated)

	SYMBOL	SSF6A G	SSF6B G	SSF6D G	SSF6F G	SSF6 GG	SSF6J G	units
Maximum Recurrent Peak Reverse Voltage	V _{rrm}	50	100	200	300	400	600	V
Maximum RMS Voltage	V _{rms}	35	70	140	210	280	420	V
Maximum DC blocking Voltage	V _{dc}	50	100	200	300	400	600	V
Maximum Average Forward Rectified Current 3/8"lead length at <u>T_a =25→C</u>	I _{f(av)}	6.0						A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{fsm}	150						A
Maximum Forward Voltage at Forward current 6A Peak	V _f	0.975			1.30		1.70	V
Maximum DC Reverse Current T _a =25→C	I _r	5.0						→A
at rated DC blocking voltage T _a =125→C		100.0						
Maximum Reverse Recovery Time (Note 1)	T _{rr}	35						nS
Typical Thermal Resistance	R _{th(ja)}	40						→C/ W
	R _{th(jl)}	5.0						
Typical Junction Capacitance (Note 2)	C _j	100			50			pF
Storage and Operating Junction Temperature	T _{stg} , T _j	-55 to +150						→C

Note:

- Reverse Recovery Condition I_f =0.5A, I_r =1.0A, I_{rr} =0.25A
- Measured at 1.0 MHz and applied reverse voltage of 4.0V_{dc}

RATINGS AND CHARACTERISTIC CURVES SSF6AG THRU SSF6JG

FIG.1 FORWARD CURRENT DERATING CURVE

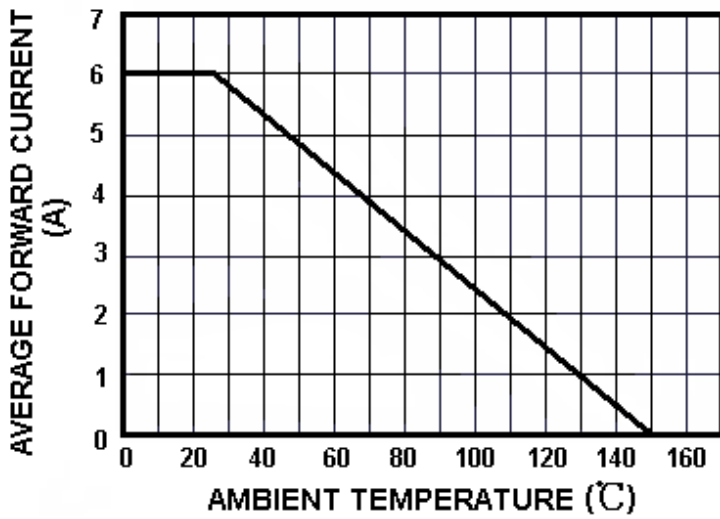


FIG.2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

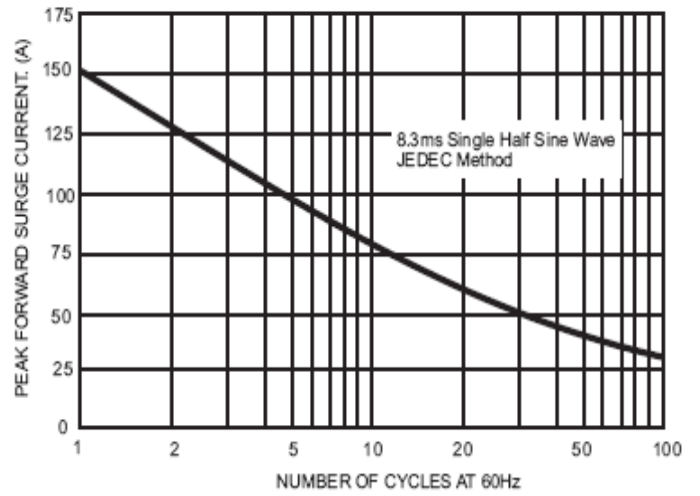


FIG.3 TYPICAL FORWARD CHARACTERISTICS

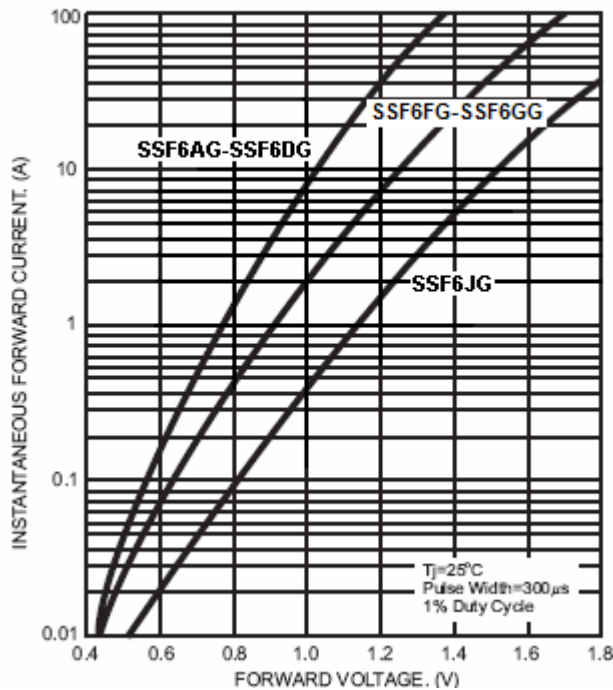


FIG.4 TYPICAL REVERSE CHARACTERISTICS

